

PC829 Series

※ TÜV (VDE0884) approved type is also available as an option.

■ Features

1. Symmetrical terminal configuration

PC829 : 2-channel type

PC849 : 4-channel type

2. High current transfer ratio

(CTR : MIN. 50% at $I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$)

3. High isolation voltage between input and output ($V_{iso} : 5000\text{V}_{rms}$)

4. Recognized by UL, file No. E64380

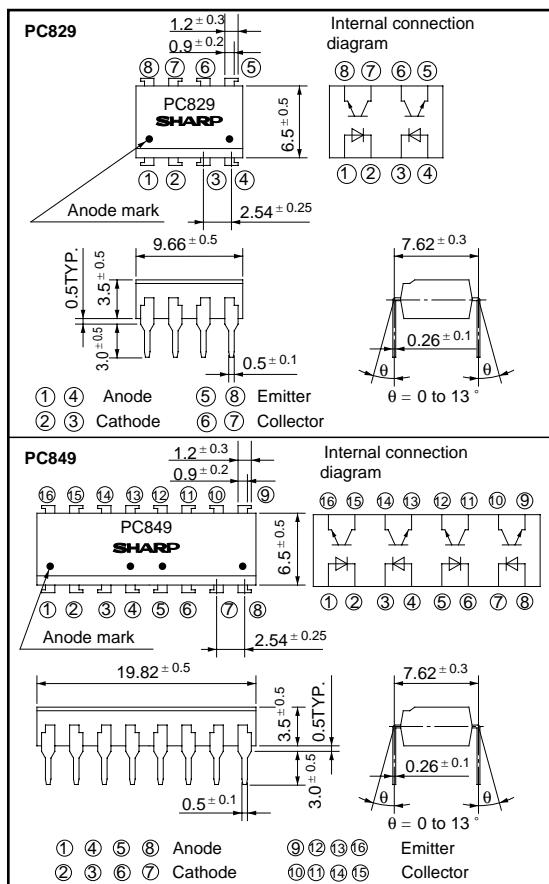
■ Applications

1. Telephone exchangers
2. Computer terminals
3. System appliances, measuring instruments
4. Signal transmission between circuits of different potentials and impedances

High Density Mounting Type Photocoupler

■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings (Ta = 25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
	*1Peak forward current	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V_{CEO}	35	V
	Emitter-collector voltage	V_{ECO}	6	V
	Collector current	I_C	50	mA
	Collector power dissipation	P_C	150	mW
Total power dissipation				
P_{tot}				
*2Isolation voltage				
V_{iso}				
Operating temperature				
T_{opr}				
Storage temperature				
T_{stg}				
*3Soldering temperature				
T_{sol}				

*1 Pulse width <= 100μs, Duty ratio : 0.001

*2 40 to 60% RH, AC for 1 minute

*3 For 10 seconds

¹ In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that occur in equipment using any of SHARP's devices, shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest version of the device specification sheets before using any SHARP's device."

■ Electro-optical Characteristics

(Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F = 20mA	-	1.2	1.4	V
	Peak forward voltage	V _{FM}	I _{FM} = 0.5A	-	-	3.0	V
	Reverse current	I _R	V _R = 4V	-	-	10	μA
	Terminal capacitance	C _t	V = 0, f = 1kHz	-	30	250	pF
Output	Collector dark current	I _{CEO}	V _{CE} = 20V, I _F = 0	-	-	10 ⁻⁷	A
Transfer characteristics	Current transfer ratio	CTR	I _F = 5mA, V _{CE} = 5V	50	-	400	%
	Collector-emitter saturation voltage	V _{CE(sat)}	I _F = 20mA, I _C = 1mA	-	0.1	0.2	V
	Isolation resistance	R _{ISO}	DC500V, 40 to 60% RH	5 × 10 ¹⁰	10 ¹¹	-	Ω
	Floating capacitance	C _f	V = 0, f = 1MHz	-	0.6	1.0	pF
	Cut-off frequency	f _c	V _{CE} = 5V, I _C = 2mA, R _L = 100Ω, -3dB	-	80	-	kHz
	Response time	t _r	V _{CE} = 2V, I _C = 2mA, R _L = 100Ω	-	4	-	μs
	Fall time	t _f		-	3	-	μs

Fig. 1 Forward Current vs.
Ambient Temperature

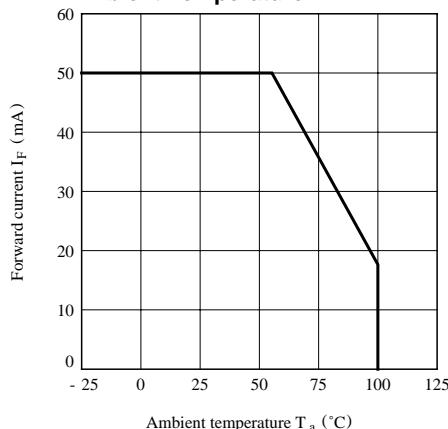


Fig. 2 Collector Power Dissipation vs.
Ambient Temperature

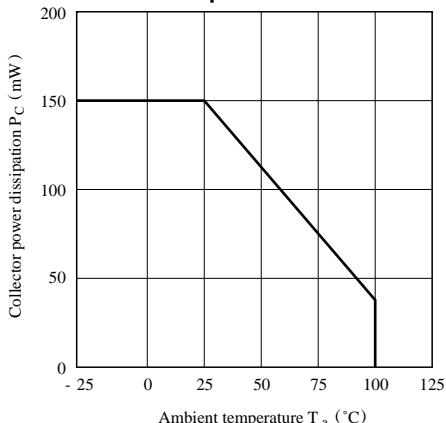


Fig. 3 Peak Forward Current vs. Duty Ratio

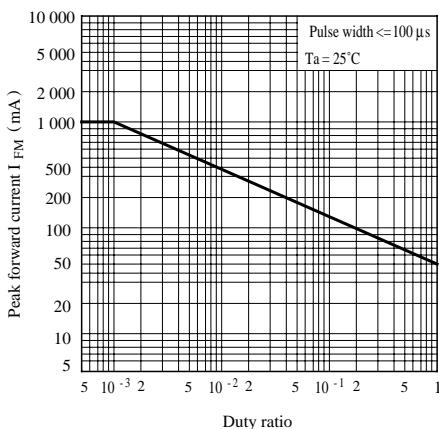


Fig. 4 Forward Current vs. Forward Voltage

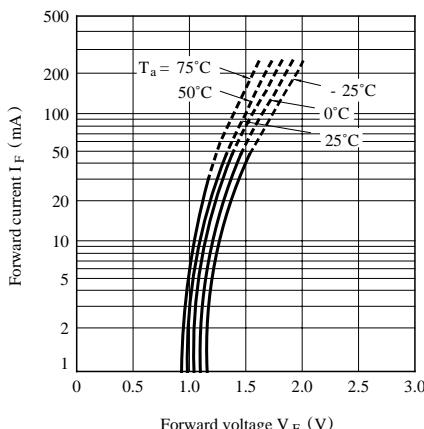


Fig. 5 Current Transfer Ratio vs. Forward Current

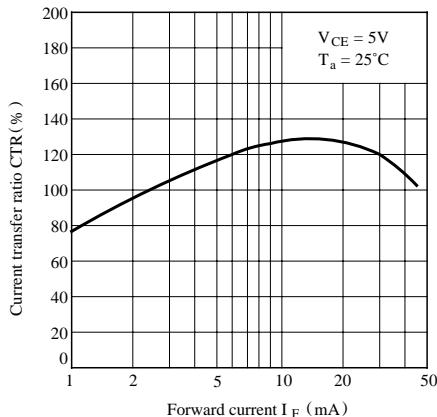


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

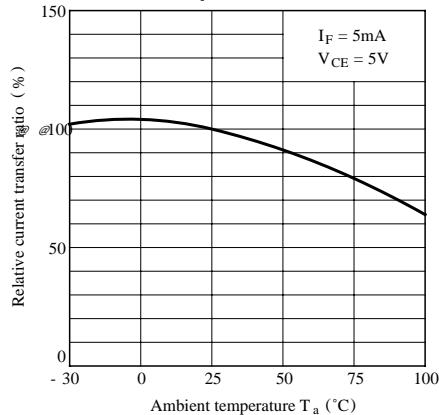


Fig. 9 Collector Dark Current vs. Ambient Temperature

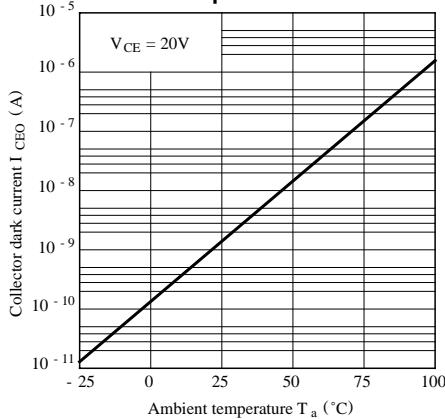


Fig. 6 Collector Current vs. Collector-emitter Voltage

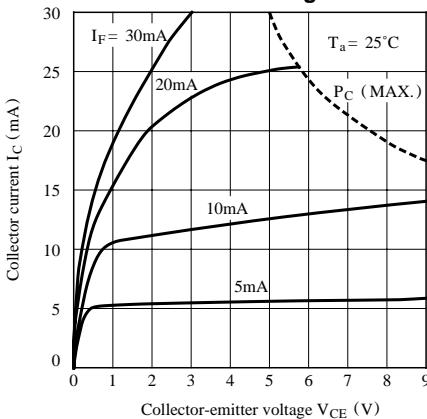


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

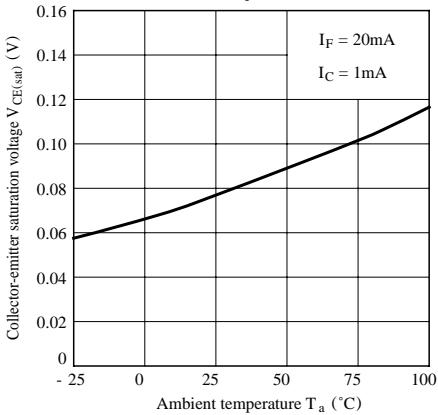


Fig. 10 Response Time vs. Load Resistance

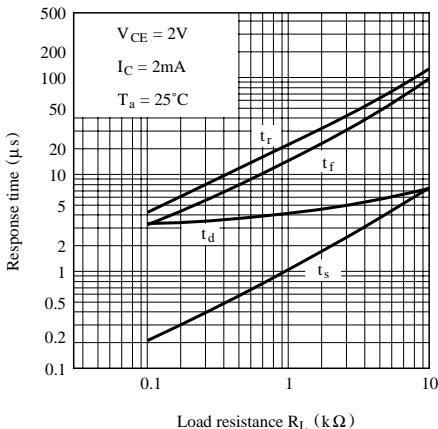
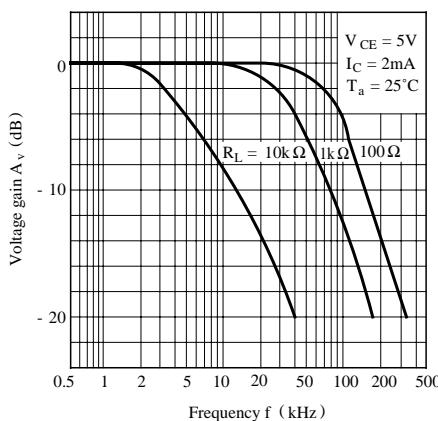
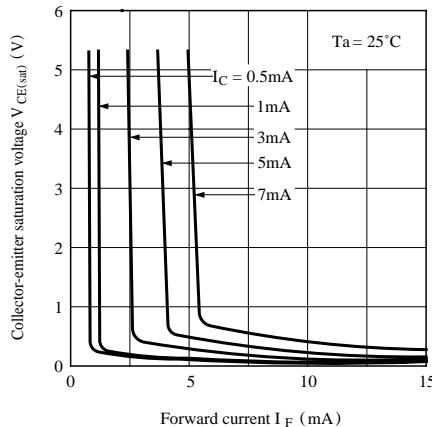
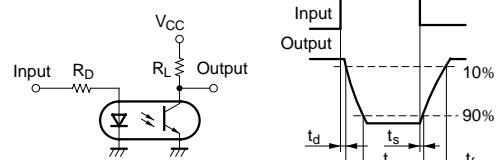
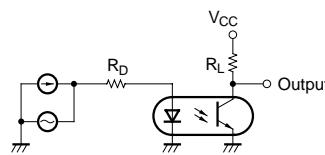


Fig.11 Frequency Response**Fig.12 Collector-emitter Saturation Voltage vs. Forward Current****Test Circuit for Response Time****Test Circuit for Frequency Response**

- Please refer to the chapter "Precautions for Use"